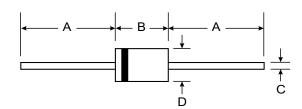


2.0A SCHOTTKY BARRIER RECTIFIER

Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 50A Peak
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Plastic Material UL Flammability Classification 94V-0



DO-41 Plastic				
Dim	Min	Max		
Α	25.40	_		
В	4.06	5.21		
С	0.71	0.864		
D	2.00	2.72		
All Dimensions in mm				

Mechanical Data

Case: Molded Plastic

 Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

Polarity: Cathode Band

Weight: 0.4 grams (approx.)

Mounting Position: Any

Marking: Type Number

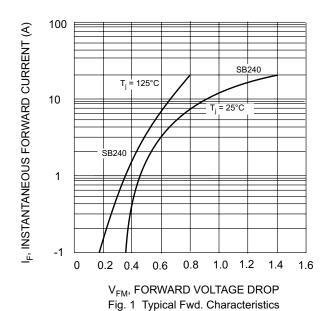
Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

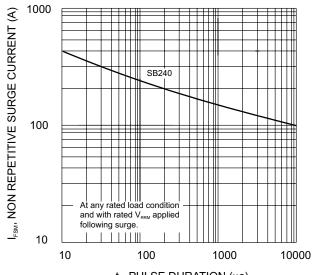
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SB240	SB260	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	60	V
RMS Reverse Voltage	V _{R(RMS)}	28	42	V
Average Rectified Output Current (Note 1) @ T _A = 25°C	lo	2.0		Α
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		50		А
Forward Voltage @ I _F = 2.0A	V _{FM}	0.50	0.70	٧
Peak Reverse Current at Rated DC Blocking Voltage @T _A = 25°C	I _{RM}	0.5		mA
Typical Junction Capacitance (Note 2)	Cj	1	90	pF
Operating and Storage Temperature Range		-55 to +125		°C

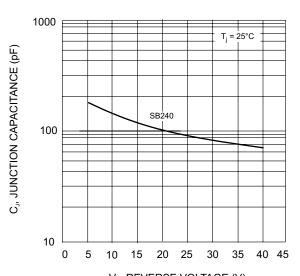
Notes: 1. Pulse width \leq 300 μ s, duty cycle \leq 2%.

2. Measured at 1.0 MHz and applied reverse voltage of 5.0V DC.





 $t_{\mbox{\tiny P}}, \mbox{ PULSE DURATION (}\mu\mbox{s})$ Fig. 2 Max Non-Repetitive Surge Current



 $V_{\mbox{\tiny R}},$ REVERSE VOLTAGE (V) Fig. 3, Typ. Junction Capacitance vs Reverse Voltage